

FORM PTO-1449	SERIAL NO. 10/782,164	CASE NO. 10322/66
LIST OF PATENTS AND PUBLICATIONS FOR APPLICANT'S INFORMATION DISCLOSURE STATEMENT	FILING DATE February 19, 2004	GROUP ART UNIT 2821
(use several sheets if necessary)		APPLICANT(S): J. Gary Eden et al.

REFERENCE DESIGNATION

U.S. PATENT DOCUMENTS

EXAMINER INITIAL	DOCUMENT NUMBER <small>Number-Kind Code (if known)</small>	DATE	NAME	CLASS/ SUBCLASS	FILING DATE

FOREIGN PATENT DOCUMENTS

EXAMINER INITIAL	DOCUMENT NUMBER <small>Number-Kind Code (if known)</small>	DATE	COUNTRY	CLASS/ SUBCLASS	TRANSLATION YES OR NO

EXAMINER INITIAL	OTHER ART - NON PATENT LITERATURE DOCUMENTS <small>(Include name of author, title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date page(s), volume-issue number(s), publisher, city and/or country where published.</small>	
MA	B1	S.-J. Park, J. Chen, C. Liu, and J. G. Eden, "Silicon microdischarge devices having inverted pyramidal cathodes: Fabrication and performance of arrays," <i>Appl. Phys. Lett.</i> , vol. 78, pp. 419-421, January 22, 2001.
MA	B2	S.-J. Park, C. J. Wagner, and J. G. Eden, "Performance of microdischarge devices and arrays with screen electrodes," <i>IEEE Photon. Tech. Lett.</i> , vol. 13, pp. 61-63, January 2001.
MA	B3	C. J. Wagner, S.-J. Park, and J. G. Eden, "Excitation of a microdischarge with a reverse-biased <i>pn</i> junction," <i>Appl. Phys. Lett.</i> , vol. 78, pp. 709-711, February 12, 2001.
MA	B4	S.-J. Park, J. Chen, C. Liu, and J. G. Eden, "Arrays of microdischarge devices having 50-100 μ m square pyramidal Si anodes and screen anodes," <i>Electron. Lett.</i> , vol. 37, pp. 171-172, February 1, 2001.
MA	B5	B. A. Vojak, S.-J. Park, C. J. Wagner, J. G. Eden, R. Koripella, J. Burdon, F. Zenhausern, and D. Wilcox, "Multistage, monolithic ceramic microdischarge device having an active length of ~ 0.27 mm," <i>Appl. Phys. Lett.</i> , vol. 78, no. 10, pp. 1340-1342, March 5, 2001.
MA	B6	S.-J. Park, J. G. Eden, J. Chen, and C. Liu, "Independently addressable subarrays of silicon microdischarge devices: Electrical characteristics of large (30 \times 30) arrays and excitation of a phosphor," <i>Appl. Phys. Lett.</i> , vol. 79, pp. 2100-2102, September 24, 2001.

EXAMINER <i>MA</i>	DATE CONSIDERED 12/09/04
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EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.